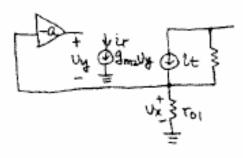
Homework Assignment No. 11 - Solutions

Problem 1 - (10 points)

Problem 8.26 of GHLM

(a) gmz is the controlled source.



Rout (gmz=0) = ro1+ro2

 $R(short) = (roll(roz)(a+1)g_{mz}$

R(open)=0

Rout = Rout($g_{mz}=0$) $\frac{1+R(short)}{1+R(open)}$

= (ro1+to2) 1+ (toiltoz) (a+1) gm2

= To1+ TO2+ (Q+1) 9m, To1 TO2

~ agmz roitoz

(b) a is the controlled source.

 $\frac{V_k}{r_{01}} = g_{mz} v_x + \frac{v_k - v_k}{r_{02}}$ Rout (9=0)= 1= 1

= 9mz To1 To2 + To1 - To2

2gm2 to 1 to 2

The output is short

Ux = gmz(VE-Vx)(ToillToz)

Ux = fm2(Toill Toz) Ut

R(short) = a gmz(to11/to2)

R(open) = 0 (Ux = 0 when the output

is open)

Rout=Rout(a=0) (+R(short)) 1+R(open) 1+a (+gmz(to))(toz) 2+gmz(to)(toz) 1+0

~ agmz roiroz

(C) The results are the same, as they should be, even though the terms Rout (k=0), R(open), and R(short) differ in (a) and (b).

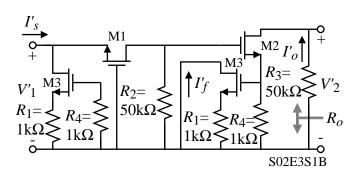
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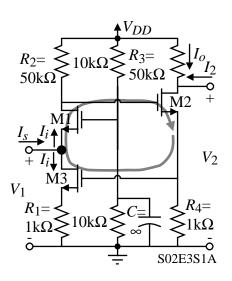
Problem 2 - (10 points)

The simplified schematic of a feedback amplifier is shown. Use the method of feedback analysis to find V_2/V_1 , $R_{in} = V_1/I_1$, and $R_{out} = V_2/I_2$. Assume that all transistors are matched and that $g_m = 1 \, \text{mA/V}$ and $r_{ds} = \infty$.

Solution

This feedback circuit is shunt-series. We begin with the open-loop, quasi-ac model shown below.





 $g_{m1}V_{gs1}$

 V_{gs1}

The small-signal, open-loop model is:

$$\frac{I_o'}{I_s'} = \left(\frac{I_o'}{V_{gs2}}\right) \left(\frac{V_{gs2}}{V_{gs1}}\right) \left(\frac{V_{gs1}}{I_s'}\right)$$

$$V_{gs2} = -g_{m1}V_{gs1}R_2 - g_{m2}V_{gs2}R_4$$

Or

$$\frac{V_{gs2}}{V_{gs1}} = \frac{-g_{m1}R_2}{1 + g_{m2}R_4} = -\frac{50}{2} = -25$$

$$\therefore \quad a = \frac{I_o'}{I_s'} = (g_{m2})(-25)\left(\frac{-1}{g_{m1}}\right) = 25\text{A/A}$$

$$f = \frac{I_f^{\prime}}{I_o^{\prime}} = \left(\frac{I_f^{\prime}}{V_{gs3}}\right) \left(\frac{V_{gs3}}{I_o^{\prime}}\right) = (g_{m3}) \left(\frac{R_4}{1 + g_{m3}R_1}\right) = (1\text{mA/V})(0.5\text{k}\Omega) = 0.5$$

$$\therefore af = 25.0.5 = 12.5$$

$$R_i = \frac{v_1'}{I_s'} = \frac{1}{g_{m1}} = 1 \text{k}\Omega \rightarrow R_{in} = R_{if} = \frac{R_i}{1 + af} = \frac{1000}{13.5} = 74.07\Omega$$

 $R_{out} = 50 \text{k}\Omega$ (R_3 is outside the feedback loop)

$$\frac{I_o}{I_s} = \frac{a}{1+af} = \frac{25}{1+12.5} = 1.852 \text{ A/A} \rightarrow \boxed{\frac{v_2}{v_1} = \frac{I_o(-50\text{k}\Omega)}{I_s(74.07\Omega)} = -1240.1 \text{ V/V}}$$

Problem 3 - (10 points)

(a) The basic amplifier without the feedback signal inserted at the inverting input of the spamp

$$q_{ml} = \frac{2}{2\sqrt{124} + \sqrt{58}} q_{m} = \frac{2}{2\sqrt{124}} q_{m}$$

$$= \frac{0.3}{2\sqrt{12} \times 0.3} + 2 \times 0.3 = 8.1 \times 10^{4} \text{ A/V}$$

$$a = \frac{v_0}{v_i} = av \frac{g_m}{g_{m+}g_{mb}}$$

$$af = a_0 \frac{g_m}{g_m + g_{mb}} = 1000 \frac{42}{4.2 + 0.81} = 838$$

$$A = \frac{a}{1+af} = \frac{838}{1+838} = 0.999$$

$$= \frac{1}{4:2\times 10^{-3} + 8.1\times 10^{-4} + 8.38}$$
$$= 0.238.\Omega$$

$$V_0 = g_m(v_k - V_0)(\frac{1}{g_{mb}}||Ri)$$

$$V_0 = \frac{g_m}{\frac{1}{R_L} + \frac{2}{3}m + \frac{2}{9mb}}$$

$$R = a_0 \frac{g_m}{\frac{1}{R_c} + g_m + g_{mb}}$$

$$\approx a_0 \frac{g_m}{g_m + g_{mb}}$$

$$A_{co} = \frac{V_O}{V_L}|_{A_{v=0}} = |(V_1 = 0 \text{ and } V_O = V_L)$$

$$= \frac{9mt9mb}{Ri+\frac{1}{9m+9mb}}$$

$$A = A_{\infty} \frac{Q}{1+Q} + \frac{d}{1+Q}$$

$$= 1 \frac{838}{1+638} + \frac{200000^{-4}}{1+638}$$

<u>Problem 3 – Continued</u>

$$R_{in}(a_{v}=0) = R_{i} + \frac{1}{4} \frac{1}{9} \frac{1}{9} \times R_{i} = 10 \text{ M} \text$$

Problem 4 - (10 points)

Use the Blackman's formula (see below) to calculate the small-signal output resistance of the stacked MOSFET configuration having identical drain-source drops for both transistors. Express your answer in terms of all the pertinent small-signal parameters and then simplify your answer if $g_m > g_{ds} > (1/R)$. Assume the MOSFETs are identical.

$$R_{out} = R_{out} (g_m = 0) \left[\frac{1 + RR(\text{output port shorted})}{1 + RR(\text{output port open})} \right]$$

(You may use small-signal analysis if you wish but this circuit seems to be one of the rare cases where feedback analysis is more efficient.)



$$R_{out}(g_{m2}=0) = 2R||(r_{ds1}+r_{ds2}) = \frac{2R(r_{ds1}+r_{ds2})}{2R+r_{ds1}+r_{ds2}}$$

RR(port shorted) = ?

$$v_r = 0 - v_{s2} = -g_{m2}v_t \left(\frac{r_{ds1}r_{ds2}}{r_{ds1} + r_{ds2}}\right)$$

$$\Rightarrow RR(\text{port shorted}) = \frac{g_{m2}r_{ds1}r_{ds2}}{r_{ds1} + r_{ds2}}$$

RR(port open) = ?

$$v_r = -g_{m2}v_t \left(\frac{r_{ds2}(r_{ds1} + R)}{r_{ds1} + r_{ds2} + 2R} \right)$$

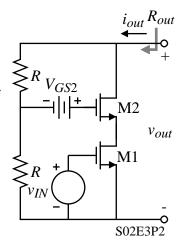
$$\Rightarrow RR(\text{port open}) = \frac{g_{m2}r_{ds2}(r_{ds1}+R)}{r_{ds1}+r_{ds2}+2R}$$

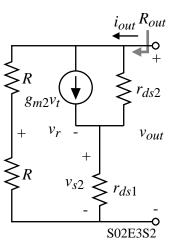
$$\therefore R_{out} = \frac{2R(r_{ds1} + r_{ds2})}{2R + r_{ds1} + r_{ds2}} \left[\frac{1 + \frac{g_{m2}r_{ds1}r_{ds2}}{r_{ds1} + r_{ds2}}}{1 + \frac{g_{m2}r_{ds2}(r_{ds1} + R)}{r_{ds1} + r_{ds2} + 2R}} \right] = 2R \left(\frac{r_{ds1} + r_{ds2} + g_{m2}r_{ds1}r_{ds2}}{r_{ds1} + r_{ds2} + 2R + g_{m2}r_{ds2}(r_{ds1} + R)} \right)$$

Using the assumptions of $g_m > g_{ds} > (1/R)$ we can simplify R_{out} as

$$R_{out} \approx 2R \left(\frac{g_{m2}r_{ds1}r_{ds2}}{g_{m2}r_{ds2}R} \right) = \underline{2r_{ds1}}$$

What is the insight? Well there are two feedback loops, one a series (the normal cascode) and one a shunt. Apparently they are working against each other and the effective output resistance is pretty much what it would be if there were two transistors in series without any feedback.



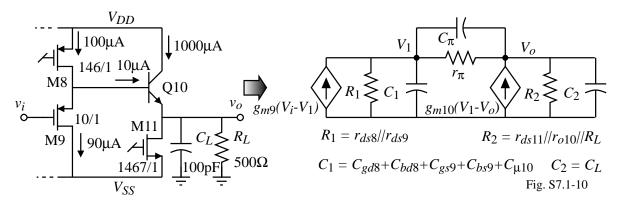


Problem 5 - (10 points)

Find the dominant roots of the MOS follower and the BJT follower for the buffered, class-A op amp of Ex. 7.1-2. Use the capacitances of Table 3.2-1. Compare these root locations with the fact that GB = 5 MHz? Assume the capacitances of the BJT are $C_{\pi} = 10 \text{pf}$ and $C_{\mu} = 1 \text{pF}$.

Solution

The model of just the output buffer of Ex. 7.1-2 is shown.



The nodal equations can be written as,

$$\begin{split} g_{m9}V_i &= (g_{m9} + G_1 + g_{\pi 10} + sC_{\pi 10} + sC_1)V_1 - (g_{\pi 10} + sC_{\pi 10})V_o \\ 0 &= -(g_{m10} + g_{\pi 10} + sC_{\pi 10})V_1 + (g_{m10} + G_2 + g_{\pi 10} + sC_{\pi 10} + sC_2)V_o \end{split}$$

Solving for V_o/V_i gives,

$$\frac{V_o}{V_i} = \frac{g_{m9}(g_{m10} + g_{\pi 10} + sC_{\pi 10})}{(g_{\pi 10} + sC_{\pi 10})(g_{m9} + G_1 + G_2 + sC_1 + sC_2) + (g_{m10} + G_2 + sC_2)(g_{m9} + G_1 + sC_1)}$$

$$\frac{V_o}{V_i} = \frac{g_{m9}(g_{m10} + g_{\pi 10} + sC_{\pi 10})}{a_0 + sa_1 + s^2a_2}$$

where

$$\begin{split} a_0 &= g_{m9}g_{\pi 10} + g_{\pi 10}G_1 + g_{\pi 10}G_2 + g_{m9}g_{m10} + g_{m10}G_1 + g_{m9}G_2 + G_1G_2 \\ a_1 &= g_{m9}C_{\pi 10} + G_1C_{\pi 10} + G_2C_{\pi 10} + g_{\pi 10}C_1 + g_{\pi 10}C_2 + g_{m10}C_1 + G_2C_1 + g_{m9}C_2 + G_1C_2 \\ a_2 &= C_{\pi 10}C_1 + C_{\pi 10}C_2 + C_1C_2 \end{split}$$

The numerical value of the small signal parameters are:

$$\begin{split} g_{m10} = & \frac{1 \, \text{mA}}{25.9 \, \text{mV}} = 38.6 \, \text{mS}, \ G_2 = 2 \, \text{mS}, \ g_{\pi 10} = 386 \, \mu \text{S}, \ g_{m9} = \sqrt{2 \cdot 50 \cdot 10 \cdot 90} = \ 300 \, \mu \text{S}, \\ G_1 = & g_{ds8} + g_{ds9} = 0.05 \cdot 100 \, \mu \text{A} + 0.05 \cdot 90 \, \mu \text{A} = 9.5 \, \mu \text{S} \\ C_2 = & 100 \, \text{pF}, \ C_{\pi 10} = 10 \, \text{pF}, \ C_1 = C_{gs9} + C_{bs9} + C_{bd8} + C_{gd8} + C_{\mu 10} \\ C_{gs9} = & C_{ov} + 0.667 C_{ox} W_9 L_9 = (220 \, \text{x} \, 10^{-12}) (10 \, \text{x} \, 10^{-6}) + 0.667 (24.7 \, \text{x} \, 10^{-4}) (10 \, \text{x} \, 10^{-12}) = 18.7 \, \text{fF} \end{split}$$

Problem 5 – Continued

$$C_{bs9} = 560 \times 10^{-6} (30 \times 10^{-12}) + 350 \times 10^{-12} (26 \times 10^{-6}) = 25.9 \text{fF}$$

(Assumed area= 3μ mx 10μ m = 30μ m and perimeter is 3μ m+ 10μ m+ 3μ m+ 10μ m = 26μ m)

$$C_{bd8} = 560 \times 10^{-6} (438 \times 10^{-12}) + 350 \times 10^{-12} (298 \times 10^{-6}) = 349 \text{fF}$$

$$C_{gd8} = C_{ov} = (220 \times 10^{-12})(146 \times 10^{-6}) = 32.1 \text{fF}$$

$$C_1 = 18.7 \text{fF} + 25.9 \text{fF} + 349 \text{fF} + 32.1 \text{fF} + 1000 \text{fF} = 1.43 \text{pF}$$

(We have ignored any reverse bias influence on pn junction capacitors.)

The dominant terms of a_0 , a_1 , and a_2 based on these values are shown in boldface above.

$$\therefore \frac{V_o}{V_i} \approx \frac{g_{m9}(g_{m10} + g_{\pi 10} + sC_{\pi 10})}{g_{m9}g_{m10} + g_{\pi 10}G_2 + s(G_2C_{\pi 10} + g_{\pi 10}C_2 + g_{m10}C_1 + g_{m9}C_2) + s^2C_2C_{\pi 10}}$$

$$\frac{V_o}{V_i} = \frac{g_{m9}g_{m10}}{g_{m9}g_{m10} + g_{\pi 10}G_2} \left[\frac{1 + \frac{sC_{\pi 10}}{g_{m10}}}{1 + s\left(\frac{G_2C_{\pi 10} + g_{\pi 10}C_2 + g_{m10}C_1 + g_{m9}C_2}{g_{m9}g_{m10} + g_{\pi 10}G_2}\right) + s^2 \frac{C_2C_{\pi 10}}{g_{m9}g_{m10} + g_{\pi 10}G_2} \right]$$

Assuming negative real axis roots widely spaced gives,

$$p_1 = -\frac{1}{a} = \frac{-(g_{m9}g_{m10} + g_{\pi 10}G_2)}{G_2C_{\pi 10} + g_{\pi 10}C_2 + g_{m10}C_1 + g_{m9}C_2} = -\frac{1.235 \times 10^{-5}}{1.465 \times 10^{-13}} = \frac{-84.3 \times 10^6 \text{ rads/sec.}}{1.465 \times 10^{-13}}$$

= -13.4MHz

$$p_2 = -\frac{a}{b} = \frac{-(G_2C_{\pi 10} + g_{\pi 10}C_2 + g_{m10}C_1 + g_{m9}C_2)}{C_2C_{\pi 10}} = -\frac{1.465 \times 10^{-13}}{100 \times 10^{-12} \cdot 10 \times 10^{-12}}$$

$$= \underline{-146.5 \text{ x} 10^6 \text{ rads/sec.}} \rightarrow -23.32 \text{MHz}$$

$$z_1 = -\frac{g_{m10}}{C_{\pi 10}} = -\frac{38.6 \times 10^{-3}}{10 \times 10^{-12}} = \frac{-3.86 \times 10^9 \text{ rads/sec.}}{10 \times 10^{-12}} \rightarrow -614 \text{MHz}$$

We see that neither p_1 or p_2 is greater than 10GB if GB = 5MHz so they will deteriorate the phase margin of the amplifier of Ex. 7.1-2.